

### **General Description**

The MAX4613 quad analog switch features on-resistance matching ( $4\Omega$  max) between switches and guarantees on-resistance flatness over the signal range (9 $\Omega$ max). This low on-resistance switch conducts equally well in either direction. It guarantees low charge injection (10pC max), low power consumption (35µW max), and an electrostatic discharge (ESD) tolerance of 2000V minimum per Method 3015.7. The new design offers lower off-leakage current over temperature (less than 5nA at +85°C).

The MAX4613 quad, single-pole/single-throw (SPST) analog switch has two normally closed switches and two normally open switches. Switching times are less than 250ns for ton and less than 70ns for toff. Operation is from a single +4.5V to +40V supply or bipolar ±4.5V to ±20V supplies.

### **Applications**

Sample-and-Hold Circuits Test Equipment Heads-Up Displays Guidance and Control Systems Military Radios

Communication Systems Battery-Operated Systems

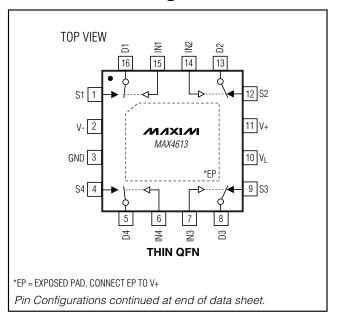
PBX, PABX

Audio Signal Routing Modems/Faxes

## **Features**

- ♦ Pin Compatible with Industry-Standard DG213
- **♦** Guaranteed Ron Match Between Channels (4 $\Omega$  max)
- ♦ Guaranteed RFLAT(ON) Over Signal Range (9 $\Omega$  max)
- ♦ Guaranteed Charge Injection (10pC max)
- **♦ Low Off-Leakage Current Over Temperature** (<5nA at +85°C)
- ♦ Withstands 2000V min ESD, per Method 3015.7
- ♦ Low RDS(ON) (85 $\Omega$  max)
- ♦ Single-Supply Operation +4.5V to +40V Bipolar-Supply Operation ±4.5V to ±20V
- ♦ Low Power Consumption (35µW max)
- ♦ Rail-to-Rail Signal Handling
- **♦ TTL/CMOS-Logic Compatible**

## **Pin Configurations/** Functional Diagrams/TruthTable



## **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX4613CPE	0°C to +70°C	16 Plastic DIP
MAX4613CSE	0°C to +70°C	16 Narrow SO
MAX4613CEE	0°C to +70°C	16 QSOP
MAX4613CUE	0°C to +70°C	16 TSSOP**
MAX4613CC/D	0°C to +70°C	Dice*
MAX4613ETE	-40°C to +85°C	16 TQFN-EP*** (5mm x 5mm)
MAX4613EPE	-40°C to +85°C	16 Plastic DIP
MAX4613ESE	-40°C to +85°C	16 Narrow SO
MAX4613EEE	-40°C to +85°C	16 QSOP
MAX4613EUE	-40°C to +85°C	16 TSSOP**

<sup>\*</sup>Contact factory for dice specifications.

<sup>\*\*</sup>Contact factory for availability.

<sup>\*\*\*</sup>EP = Exposed Pad

#### **ABSOLUTE MAXIMUM RATINGS**

Voltage Referenced to GND	Continuous Power D
V++44	<ul><li>V Plastic DIP (derate</li></ul>
V44	V Narrow SO (derate
V+ to V+44	V QSOP (derate 8.3)
VL(GND - 0.3V) to (V+ + 0.3V	/) Thin QFN (derate
Digital Inputs V <sub>S</sub> V <sub>D</sub> (Note 1)(V 2V) to (V+ + 2V)	<ul><li>TSSOP (derate 6.7)</li></ul>
or 30mA (whichever occurs first	st) Operating Tempera
Continuous Current (any terminal)30m	A MAX4613C
Peak Current, S_ or D_	MAX4613E
(pulsed at 1ms, 10% duty cycle max)100m	A Storage Temperatur

Continuous Power Dissipation ( $T_A = +$	
Plastic DIP (derate 10.53mW/°C abov	/e +70°C)842mW
Narrow SO (derate 8.70mW/°C abov	re +70°C)696mW
QSOP (derate 8.3mW/°C above +70	°C)667mW
Thin QFN (derate 33.3mW/°C above	+70°C)2667mW
TSSOP (derate 6.7mW/°C above +70	0°C)457mW
Operating Temperature Ranges	
MAX4613C	0°C to +70°C
MAX4613E	40°C to +85°C
Storage Temperature Range	65°C to +165°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on S\_, D\_, or IN\_ exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS—Dual Supplies**

 $(V+ = 15V, V- = -15V, V_L = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDIT	IONS	MIN	TYP (Note 2)	MAX	UNITS	
SWITCH	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$							
Analog Signal Range	Vanalog	(Note 3)		-15		15	V	
Drain Source On Besistance	Process	$V_D = \pm 10V$ ,	T <sub>A</sub> = +25°C		55	70	0	
Dialii-30dice Off-Hesistance	TIDS(ON)	$I_S = 1mA$	$T_A = T_{MIN}$ to $T_{MAX}$			85	52	
On-Resistance Match	APD0(ON)	$V_D = \pm 10V$ ,	T <sub>A</sub> = +25°C			4	0	
Between Channels (Note 4)	ALIDS(ON)	Is = 1mA	TA = TMIN to TMAX			5	52	
On Posistanae Flatness (Note 4)	DEL ATION	$V_D = \pm 5V$ ,	T <sub>A</sub> = +25°C			9	0	
On-nesistance riatiless (Note 4)	nFLAT(ON)	$I_S = 1mA$	$T_A = T_{MIN}$ to $T_{MAX}$			15	52	
Source Leakage Current	lovorr)	$V_D = \pm 14V$ ,	T <sub>A</sub> = +25°C	-0.50	0.01	0.50	nΛ	
(Note 5)	IS(OFF)	$V_S = \mp 14V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	HA	
Drain-Off Leakage Current	ID (OFF)	$V_D = \pm 14V$ ,	T <sub>A</sub> = +25°C	-0.50	0.01	0.50	nΛ	
(Note 5)	ID(OFF)	$V_S = \mp 14V$	TA = TMIN to TMAX	-5		5	HA	
Drain-On Leakage Current	` ′	$V_D = \pm 14V$ ,	T <sub>A</sub> = +25°C	-0.50	0.08	0.50	Λ	
(Note 5)		$V_S = \pm 14V$	TA = TMIN to TMAX	-10		10	ΠA	
INPUT								
Input Current with Input Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 2.4V, all others = 0	).8V	-0.5	-0.00001	0.5	μΑ	
Input Current with Input Voltage Low	linl	V <sub>IN</sub> = 0.8V, all others = 2.4V		-0.5	-0.00001	0.5	μΑ	
SUPPLY								
Power-Supply Range	V+, V-			±4.5		±20.0	V	
Positive Supply Current	l+	All channels on or off,	T <sub>A</sub> = +25°C	-1	0.001	1	^	
i ositive supply Guiterit	1+	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	] μΑ	
Negative Supply Current	-	All channels on or off,	T <sub>A</sub> = +25°C	N to TMAX  15  °C  -0.50  0.01  0.50  N to TMAX  -5  5  °C  -0.50  0.01  0.50  NA  NA  NA  NA  NA  NA  NA  NA  NA  N				
riegative Supply Culterit	-	$V_{IN} = 0 \text{ or } 5V$	TA = TMIN to TMAX	-5		5	μΑ	

### **ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)**

 $(V+ = 15V, V- = -15V, V_L = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDIT	TIONS	MIN	TYP (Note 2)	MAX	UNITS
Logio Cupply Current	lı .	All channels on or off,	T <sub>A</sub> = +25°C	-1	0.001	1	
Logic Supply Current	ΙL	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	μA
Ground Current	loup	All channels on or off,	T <sub>A</sub> = +25°C	-1	-0.0001	1	μA
Ground Current	IGND	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	μΑ
DYNAMIC							
Turn-On Time (Note 3)	ton	$V_S = \pm 10V$ , Figure 2	T <sub>A</sub> = +25°C		150	250	ns
Turn-Off Time (Note 3)	toff	$V_S = \pm 10V$ , Figure 2	T <sub>A</sub> = +25°C		90	120	ns
Break-Before-Make Time Delay (Note 3)	tD	Figure 3	T <sub>A</sub> = +25°C	5	20		ns
Charge Injection (Note 3)	Q	C <sub>L</sub> = 1nF, V <sub>GEN</sub> = 0, R <sub>GEN</sub> = 0, Figure 4	T <sub>A</sub> = +25°C		5	10	рС
Off-Isolation Rejection Ratio (Note 6)	OIRR	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , Figure 5	T <sub>A</sub> = +25°C		60		dB
Crosstalk (Note 7)		$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , Figure 6	T <sub>A</sub> = +25°C		100		dB
Source-Off Capacitance	Cs(off)	f = 1MHz, Figure 7	T <sub>A</sub> = +25°C		4		pF
Drain-Off Capacitance	C <sub>D</sub> (OFF)	f = 1MHz, Figure 7	T <sub>A</sub> = +25°C		4		pF
Source-On Capacitance	C <sub>S(ON)</sub>	f = 1MHz, Figure 8	T <sub>A</sub> = +25°C		16		pF
Drain-On Capacitance	C <sub>D(ON)</sub>	f = 1MHz, Figure 8	T <sub>A</sub> = +25°C		16		pF

## **ELECTRICAL CHARACTERISTICS—Single Supply**

 $(V+ = 12V, V- = 0V, V_L = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITION	IS	MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	Vanalog			0		12	V
Drain-Source	Process	$V_L = 5V; V_D = 3V, 8V;$	T <sub>A</sub> = +25°C		100	160	Ω
On-Resistance	R <sub>DS(ON)</sub>	$I_S = 1mA$	TA = TMIN to TMAX			200	52
SUPPLY	•						
Power-Supply Range	V+, V-			4.5		40	V
Power-Supply Current	l+	All channels on or off, VIN = 0 or 5V	T <sub>A</sub> = +25°C	-1	0.001	1	μA
Fower-Supply Current			TA = TMIN to TMAX	-5		5	] μΛ
Nagativa Cupply Current		All channels on or off,	T <sub>A</sub> = +25°C	-1	-0.0001	1	
Negative Supply Current	-	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	μΑ
Lagia Cumalu Cumant	1.	All channels on or off,	T <sub>A</sub> = +25°C	-1	0.001	1	
Logic Supply Current	IL	$V_{IN} = 0 \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	μΑ
Ground Current	lava	All channels on or off,	T <sub>A</sub> = +25°C	-1	-0.0001	1	
Ground Current	IGND	V <sub>IN</sub> = 0 or 5V	TA = TMIN to TMAX	-5		5	μA

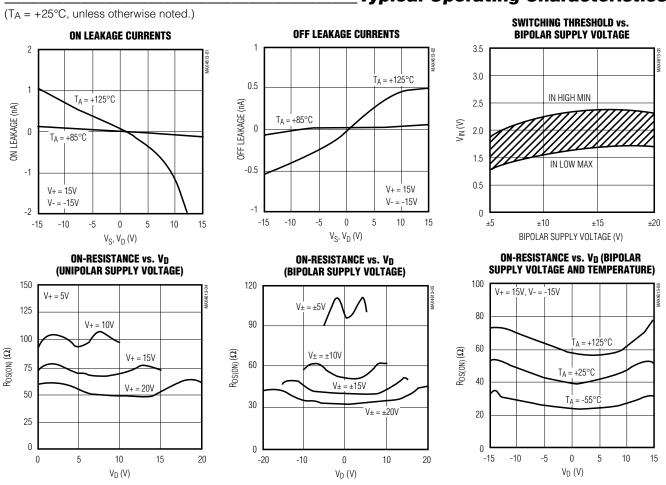
### **ELECTRICAL CHARACTERISTICS—Single Supply (continued)**

(V+ = 12V, V- = 0, VL = 5V, GND = 0V, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITION	S	MIN	TYP (Note 2)	MAX	UNITS
DYNAMIC							
Turn-On Time (Note 3)	ton	V <sub>S</sub> = 8V, Figure 2	T <sub>A</sub> = +25°C		300	400	ns
Turn-Off Time (Note 3)	toff	V <sub>S</sub> = 8V, Figure 2	T <sub>A</sub> = +25°C		60	200	ns
Charge Injection (Note 3)	Q	$C_L = 1nF$ , $V_{GEN} = 0$ , $R_{GEN} = 0$ , Figure 4	T <sub>A</sub> = +25°C		5	10	рС

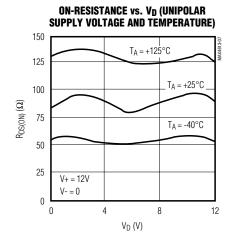
- **Note 2:** Typical values are for **design aid only,** are not guaranteed and are not subject to production testing. The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- **Note 4:** On-resistance match between channels and flatness are guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog signal range.
- Note 5: Leakage parameters IS(OFF), ID(OFF), ID(ON), and IS(ON) are 100% tested at the maximum rated hot temperature and guaranteed at +25°C.
- Note 6: Off-Isolation Rejection Ratio = 20log (V<sub>D</sub>/V<sub>S</sub>).
- Note 7: Between any two switches.

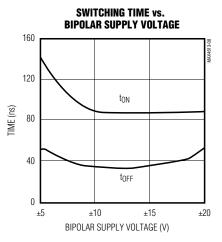
### **Typical Operating Characteristics**

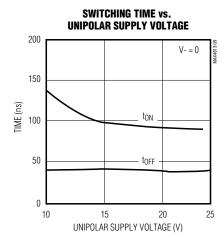


### Typical Operating Characteristics (continued)

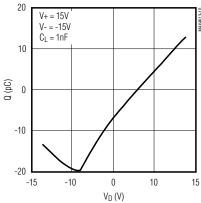
 $(T_A = +25$ °C, unless otherwise noted.)



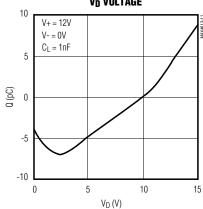




### CHARGE INJECTION vs. V<sub>D</sub> voltage



# CHARGE INJECTION vs. $V_D$ voltage



### **Pin Description**

PI	PIN		FUNCTION
DIP/SO/TSSOP	THIN QFN	NAME	FUNCTION
1, 8, 9, 16	6, 7, 14, 15	IN1-IN4	Logic Control Input
2, 7, 10, 15	5, 8, 13, 16	D1-D4	Analog-Switch Drain Output
3, 6, 11, 14	1, 4, 9, 12	S1–S4	Analog-Switch Source Output
4	2	V-	Negative-Supply Voltage Input
5	3	GND	Ground
12	10	٧L	Logic-Supply Voltage Input
13	11	V+	Positive-Supply Voltage Input—Connected to Substrate
_	EP	PAD	Exposed Pad. Connect PAD to V+.

## Applications Information

#### **General Operation**

- 1) Switches are open when power is off.
- 2) IN\_, D\_, and S\_ should not exceed V+ or V-, even with the power off.
- 3) Switch leakage is from each analog switch terminal to V+ or V-, not to other switch terminals.

### Operation with Supply Voltages Other than ±15V

Using supply voltages less than  $\pm 15V$  will reduce the analog signal range. The MAX4613 operates with  $\pm 4.5V$  to  $\pm 20V$  bipolar supplies or with a  $\pm 4.5V$  to  $\pm 40V$  single supply; connect V- to GND when operating with a single supply. Also, all device types can operate with unbalanced supplies such as  $\pm 24V$  and  $\pm 5V$ . V<sub>L</sub> must be connected to  $\pm 5V$  to be TTL compatible, or to V+ for CMOS-logic level inputs. The *Typical Operating Characteristics* graphs show typical on-resistance with  $\pm 20V$ ,  $\pm 15V$ ,  $\pm 10V$ , and  $\pm 5V$  supplies. (Switching times increase by a factor of two or more for operation at  $\pm 5V$ .)

#### **Overvoltage Protection**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V<sub>L</sub>, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V-should not exceed +44V.

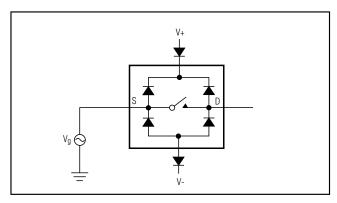


Figure 1. Overvoltage Protection Using External Blocking Diodes

### **Timing Diagrams/Test Circuits**

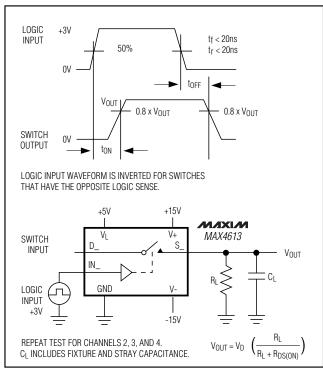


Figure 2. Switching Time

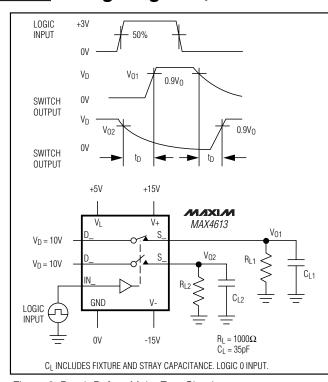


Figure 3. Break-Before-Make Test Circuit

## **Revision History**

Pages changed at Rev 3: 1, 9, 10

### Timing Diagrams/Test Circuits (continued)

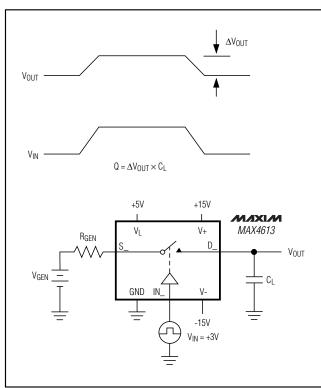


Figure 4. Charge Injection

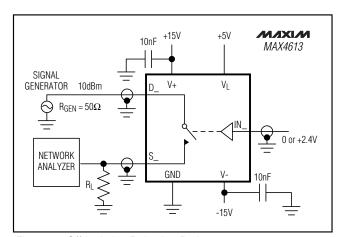


Figure 5. Off-Isolation Rejection Ratio

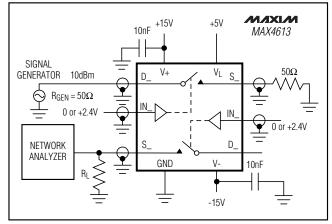


Figure 6. Crosstalk

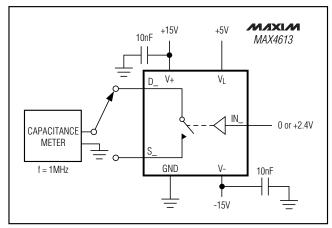


Figure 7. Source/Drain-Off Capacitance

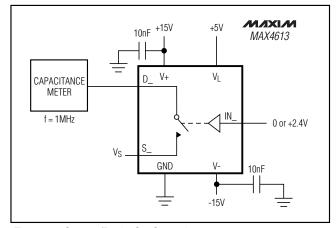
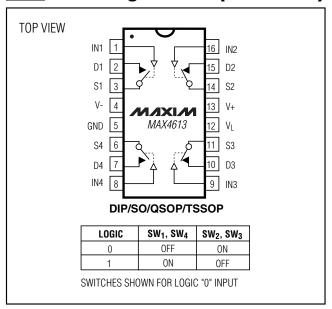


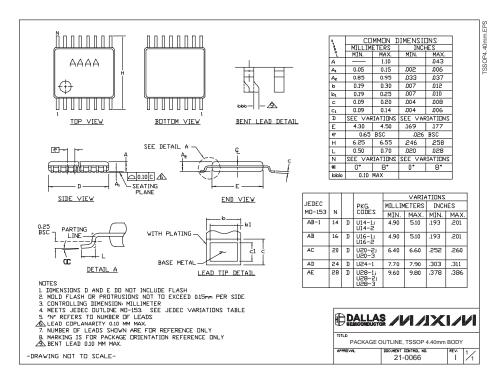
Figure 8. Source/Drain-On Capacitance

### Pin Configurations (continued)



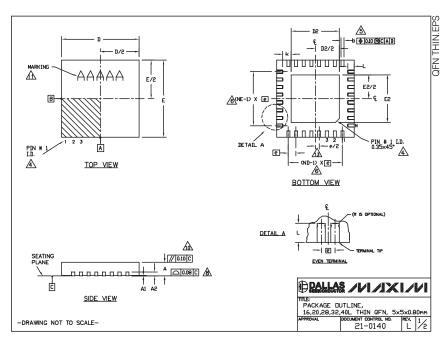
### **Package Information**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



### **Package Information (continued)**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



		COM	MON DIMENSIONS	5				EXP	OSED	PAD \	ARIAT	ZMOI	
PKG.	16L 5×5	20L 5×5	28L 5×5	32L 5×5	40L 5×5	Pk	KG.		DS			E2	$\neg$
YMBOL	MIN. NON. MAX	. HIN. NOM. HAX	. MIN. NOM. MAX.	MIN. NOM. MAX.	MIN. NOM. MAX.			MIN.	NDM.	MAX.	MIN	NDM.	MAX.
Α	0.70 0.75 0.80		0.70 0.75 0.80		0.70 0.75 0.80	T1	655-2	3.00	3.10	3.20	3.00	3.10	3.20
AI.	0 0.02 0.05	0 0.02 0.05	0 0.02 0.05	0 0.02 0.05	0 0.02 0.05	T1	655-3	3.00	3.10	3.20	3.00	3.10	3.20
A2	0.20 REF.	0.20 REF.	0.20 REF.	0.20 REF.	0.20 REF.	T1	.655N-1	3.00	3.10	3.20	3.00	3.10	3.20
b			0.20 0.25 0.30			T2	2055-3	3.00	3.10	3.20	3.00	3.10	3.20
D			4.90 5.00 5.10			Т	2055-4	3.00	3.10	3.20	3.00	3.10	3.20
E	0.80 BSC.	0.65 BSC.	4.90 5.00 5.10 0.50 BSC.	0.50 BSC.	0.40 BSC.	та	2055-5	3.15	3.25	3.35	3.15	3.25	3.35
k	0.80 BSC.			0.50 850.	0.40 BSC.	TZ	2055MN-5	315	3,25	3.35	3.15	3.25	
L		0.00	0.25			TZ	2855-3	3.15	3.25	3.35	3.15	3.25	3.35
N	16	20	28	32	40	Т	855-4	2.60	2.70	2.80	2.60	2,70	2.80
ND	4	5	7	8	10			2.60	2.70	2.80	2.60	2.70	2.80
NE	4	5	7	8	10	TZ	2955-6	3.15	3.25	3.35	3.15	3.25	3.35
JEDEC	VHHB	WHHC	WHHD-1	AHHD-5		TE	855-7	2.60	2.70	2.80	2.60	2.70	2.90
						TE	2955-8	3.15	3.25	3.35	3.15	3.25	3.35
NOTES:						та	2855N-1	3.15	3.25	3.35	3.15	3.25	3.35
	ACNOTUNING 0.	TO EDANCING O	CONFORM TO AS	ME V145M_1004	ı	TS	3255-3	3.00	3.10	3.20	3.00	3.10	3.20
			ETERS. ANGLES			<u> </u>			3.10	3.20	3.00	3.10	3.20
		NUMBER OF TE							3.10	3.20	3.00	3.10	3.20
			ND TERMINAL N	IUMBERING CON	VENTION SHALL				3.10			310	3.20
			2. DETAILS OF						3.10	3.20	3.00	3.10	3,20
			ED WITHIN THE		ed, the termi	Inc. #1			3.50	3.60	3.40	3.50	3.60
			OLD OR MARKE						3,50	3.60	3.40	3.50	3.60
		PLIES TO META ) mm FROM TER	LLIZED TERMIN	AL ANU IS MEA	ZOMETH BELMEE	1 14	4055MN-1	3.40	3.50	3.60	3.40	3.50	3.60
ND 7. DE 8. CD 9. DR 12. VA 11. MA	AND NE REFE POPULATION IS PLANARITY API AWING CONFOR 855-3, T2855- RPAGE SHALL RKING IS FOR	R TO THE NUMS POSSIBLE IN PLIES TO THE MS TO JEDEC I -6, T4055-1 AN NOT EXCEED 0 PACKAGE ORIE	BER OF TERMIN A SYMMETRICAL EXPOSED HEAT MO220, EXCEPT ID T4055-2.	L FASHION. SINK SLUG AS EXPOSED PAD ENCE ONLY.	WELL AS THE		ΩĐ	ALL	AS	41	41 4	4174	<b>(1/</b>
	AD CENTERLIN	ES TO BE AT 1	RUE POSITION H LEADED AND	AS DEFINED BY		ION 'e', ±0.05.		idanat	ictor	# b			

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